

| | Type | L # | Hits | Search Text | DBs | Time Stamp | Comments |
|---|------|-----|------|---|--|---------------------|----------|
| 1 | BRS | L1 | 6849 | IGBT or "insulated gate bipolar transistor" | USPAT; EPO; JPO; Derwent; IBM TDB | 2000/11/30 18:41 | |
| 2 | BRS | L2 | 3090 | diode and 1 | USPAT; EPO; JPO; Derwent; IBM TDB | 2000/11/30 20:37 | |